

## SANYO Semiconductors

DATA SHEET



Monolithic Linear IC For TV/VCR Use Video Switch

#### Features

- 4 inputs, 1 output,  $75\Omega$  termination, driver on-chip.
- 6dB amplifier on-chip.
- Excellent crosstalk characteristic.
- Wide band.

#### **Specifications**

#### **Maximum Ratings** at $Ta = 25^{\circ}C$

Parameter	Symbol	Conditions	Ratings	Unit				
Maximum supply voltage	V <sub>7</sub> max		14	V				
Maximum input supply voltage 1	V <sub>4</sub> max, V <sub>6</sub> max V <sub>8</sub> max, V <sub>9</sub> max		8	V				
Maximum input supply voltage 2	V <sub>2</sub> max, V <sub>3</sub> max	V <sub>CC</sub> = 14V	14	V				
Maximum output current	I <sub>1</sub> max		10	mA				
Allowable power dissipation	Pd max	Ta ≤65°C	540	mW				
Operating temperature	Topr		-20 to +65	°C				
Storage temperature	Tstg		-55 to +150	°C				
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# **Operating Conditions** at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Operating voltage range	V <sub>CC</sub> op		10.5 to 13.5	V
Recommended supply voltage	Vcc		12	V
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### Electrical Characteristics at Ta = 25°C, $V_{CC}$ = 12V

Deservator	Symbol	Conditions		Ratings		
Parameter			min	typ	max	Unit
Quiescent current drain	ICC		15	21	30	mA
Input bias voltage	V <sub>4</sub> , V <sub>6</sub> , V <sub>8</sub> , V <sub>9</sub>		3.5	3.8	4.1	V
Output bias voltage	V <sub>1</sub>		4.6	6.1	7.6	V
Output DC offset voltage	V <sub>OS</sub>	(Note 1)	-50	0	+50	mV
Control threshold voltage	V <sub>2H</sub> , V <sub>3H</sub>		2.3			V
	V <sub>2L</sub> , V <sub>3L</sub>				0.7	V
Control input current	I <sub>2</sub> , I <sub>3</sub>		-20	-6		μA
Voltage gain	GV	f = 1MHz, V <sub>IN</sub> = 2Vp-p (Note 1)	5.6	6.1	6.4	dB
Frequency characteristics	GV-f	0dB at f = 100kHz (Note 1)	-3	0		dB
		$f = 10MHz, V_{IN} = 1Vp-p$				
Output dynamic range	V <sub>DR</sub>	f = 15kHz, V <sub>IN</sub> = 1.5Vp-p (Note 1)	1.4	1.5		Ур-р
Crosstalk (Note 2)	С <sub>Т</sub>	V <sub>IN</sub> = 1Vp-p, f = 3MHz (Note 1)	50 (48)	58 (55)		dB
		V <sub>IN</sub> = 1Vp-p, f = 5MHz (Note 1)	45 (45)	55 (52)		dB

The current flowing into the IC is defined as positive and current from the IC is defined as negative.

#### Video Switch Truth Table

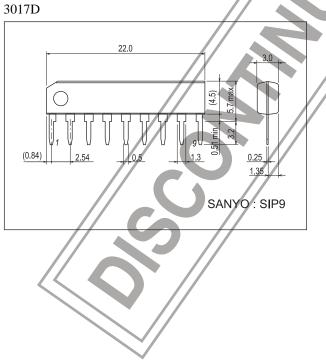
S2 (Pin 2)	S3 (Pin 3)	V <sub>IN1</sub> (Pin 4)	V <sub>IN2</sub> (Pin 6)	V <sub>IN3</sub> (Pin 8)	V <sub>IN4</sub> (Pin 9)
Н	Н	ON	OFF	OFF	OFF
L	Н	OFF	ON	OFF	OFF
Н	L	OFF	OFF	ÓN	OFF
L	L	OFF	OFF	OFF	ON

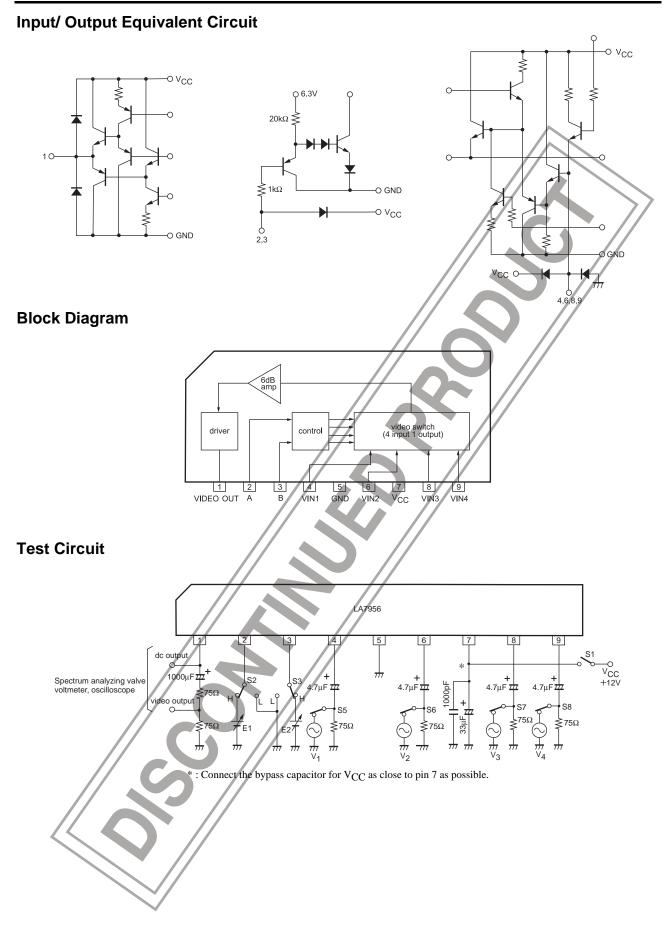
Note 1 : Refer to this Truth Table and make measurements by switching \$2, \$3

Note 2 : ( ) : Crosstalk between pins 8 and 9.

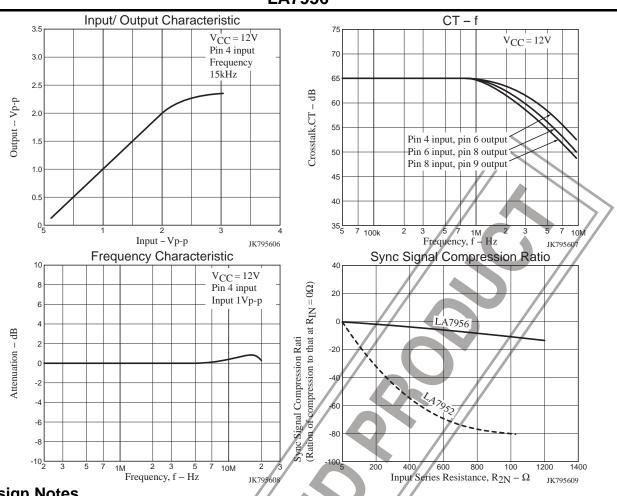
## Package Dimensions

unit : mm (typ)









#### **Design Notes**

An improvement in the DC clamp circuit has improved the sync signal compression attributable to the signal source impedance, but the response time of the DC clamp is made longer accordingly than that of the LA7952. Make adjustments by connecting a high resistance (several hundred  $k\Omega$ ) across input pin and GND (decreasing the resistance makes the sync signal compression larger).

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